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APPLICATION NO.	F	ILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
10/808,018		03/24/2004	Michael Violette	400.278US01 5683	
27073	7590	03/14/2005		EXAMINER	
LEFFERT	JAY & P	OLGLAZE, P.A.		DANG, I	PHUC T
P.O. BOX 5	81009	·			
MINNEAPO	DLIS, MN	J 55458-1009	ART UNIT	PAPER NUMBER	
				2010	

DATE MAILED: 03/14/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)				
		10/808,018	VIOLETTE, MICHAEL				
	Office Action Summary	Examiner	Art Unit				
		PHUC T. DANG	2818				
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply							
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 2 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.  - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.  - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).  Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).							
Status							
1)⊠	Responsive to communication(s) filed on elect	ion filed on February 17, 2005.					
2a) <u></u> □	This action is <b>FINAL</b> . 2b) This	action is non-final.					
3)⊠	Since this application is in condition for allowance except for formal matters, prosecution as to the ments is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims							
5)□ 6)□ 7)⊠	Claim(s) 1-39 is/are pending in the application 4a) Of the above claim(s) 20-39 is/are withdraw Claim(s) is/are allowed. Claim(s) is/are rejected. Claim(s) 1-19 is/are objected to. Claim(s) are subject to restriction and/or	vn from consideration.					
Application Papers							
9)☐ The specification is objected to by the Examiner.							
10)⊠ The drawing(s) filed on <u>24 March 2004</u> is/are: a)⊠ accepted or b)⊡ objected to by the Examiner.							
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).  11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.							
Priority under 35 U.S.C. § 119							
<ul> <li>12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).</li> <li>a) All b) Some * c) None of:</li> <li>1. Certified copies of the priority documents have been received.</li> <li>2. Certified copies of the priority documents have been received in Application No.</li> <li>3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).</li> <li>* See the attached detailed Office action for a list of the certified copies not received.</li> </ul>							
Attachmen	ut(s)						
1) Notice of References Cited (PTO-892)  4) Interview Summary (PTO-413)  Paper No(s)/Mail Date							
3) Infor	ce of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) er No(s)/Mail Date		ate Patent Application (PTO-152)				

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### **DETAILED ACTION**

#### Restriction/Election

Applicant's election filed on February 17, 2005 is acknowledged.
 In election, Applicants elected Group I (claims 1-19) and withdrawn Group II (claims 20-39).

Claims 1-39 are currently pending in this application for examination at this time.

#### Oath/Declaration

2. The oath/declaration filed on March 24, 2004 is acceptable.

## Specification

This application is in condition for allowance except for the following formal matters:

i) The title of the invention is not descriptive. A new title is required that is clearly indicative of the invention to which the claims are directed (see MPEP 606.01).

A title such as -- METHOD OF FORMING SELECT LINES FOR NAND MEMORY DEVICES -- is suggested. Note that, the claims are directed to a method of forming a semiconductor device instead of to an apparatus of a semiconductor device.

ii) Applicants are advised to cancel the non-elected claims of Group II (claims 20-39) in response to the next Office action if the application is considered to be allowed.

## Allowable Subject Matter

3. Claims 1-19 would be allowed.

The following is a statement of reason for the indication of allowable subject matter:

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None of the prior art of records suggested or discloses a method of forming a portion of a NAND memory array comprising a step of connecting first and second conductive layers of the select line that are separated by an interlayer dielectric using a contact that extends from a third conductive layer, formed on the second conductive layer, to the first conductive layer, the contact formed in a hole that passes through the second conductive layer and the interlayer dielectric layer and that terminates at the first conductive layer in combination with the other steps of the independent method of claim 1.

None of the prior art of records suggested or discloses a method of forming a portion of a NAND memory array comprising a step of forming a third conductive layer on the second conductive layer and on sidewalls of the hole and the exposed portion of the first conductive layer to form a contact in the hole that electrically connects the first and second conductive layers in combination with the other steps of the independent method of claims 7 and 12.

None of the prior art of records suggested or discloses a method of forming a portion of a NAND memory array comprising a step of forming a metal-containing layer on the second polysilicon layer and on sidewalls of the hole and the exposed portion of the first polysilicon layer to form a contact in the hole that electrically connects the first and second polysilicon layers in combination with the other steps of the independent method of claims 18 and 19.

Prosecution on the merit is closed in accordance with the practice under Ex Parte Quayle, 1935 C.D. 11, 453 O.G. 213.

A shortened statutory period for reply to this action is set to expire TWO MONTHS from the mailing date of this letter.

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Conclusion

4. Any inquiry concerning this communication or earlier communications from the examiner

should be directed to Phuc T. Dang whose telephone number is (571) 272-1776. The examiner

can normally be reached on 8:00 am-5:00 pm.

5. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor,

David C. Nelms can be reached on (571) 272-1787. The fax phone numbers for the organization

where this application or proceeding is assigned are 703-872-9306 for regular communications

and After Final communications.

6. Any inquiry of a general nature or relating to the status of this application or proceeding

should be directed to the receptionist whose telephone number is 703-308-0956.

Phuc T. Dang

PD Langshur

**Primary Examiner** 

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